

Features

- Electrical isolation between chip and base plate, 2500V AC insulator
- Excellent temperature characteristics and power cycling capability
- Compact size and lightweight

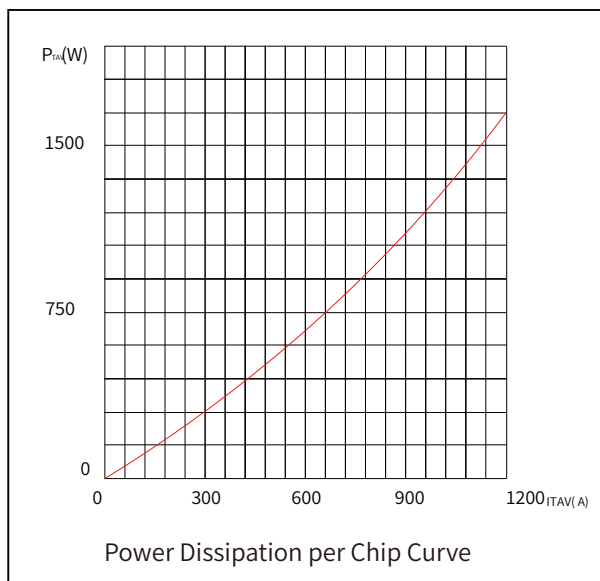
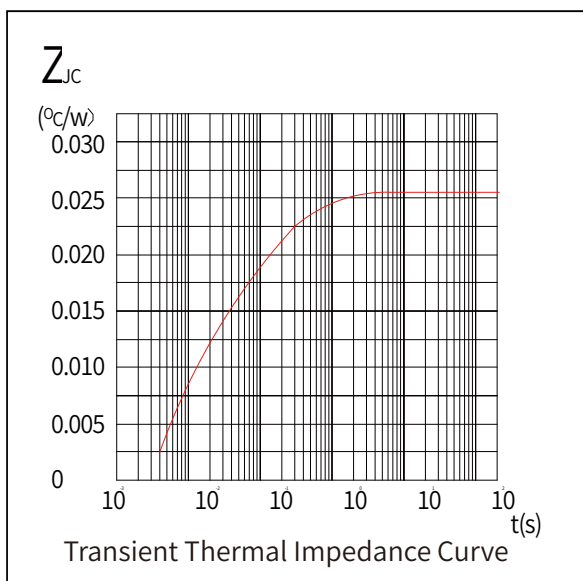
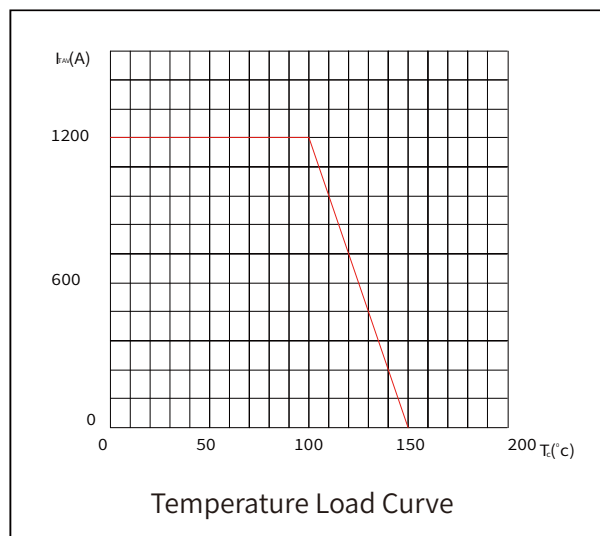
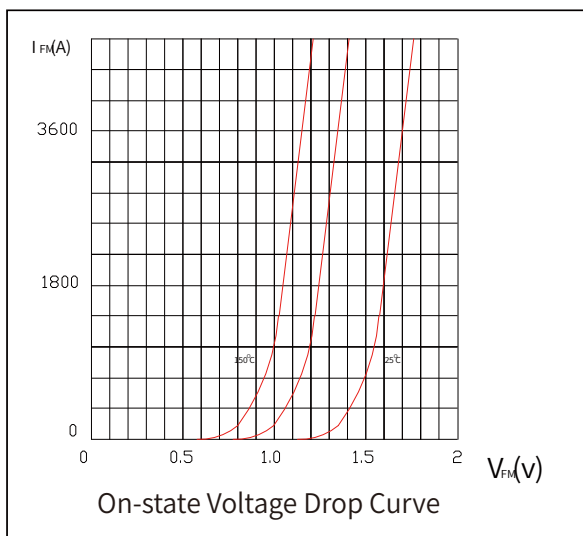
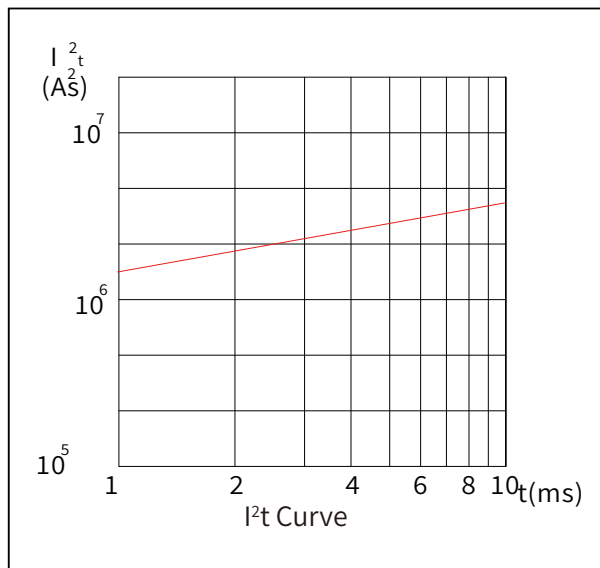
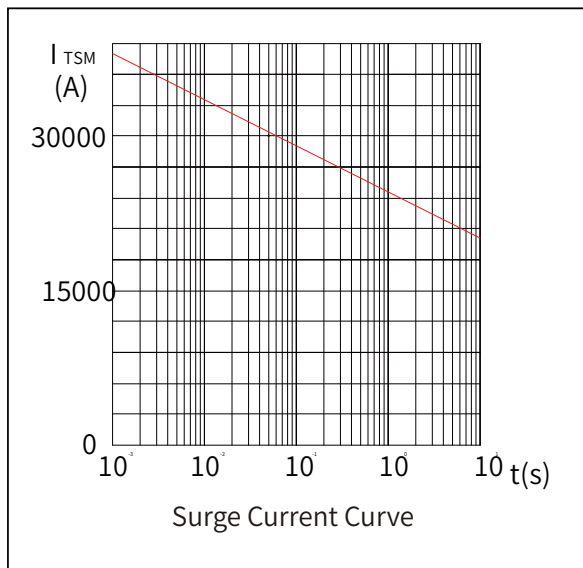
Applications

- AC/DC motor control
- Various rectifier power supplies
- Frequency converters



$V_{RSM}(V)$	$V_{RRM}(V)$	Model
1300	1200	MTC1200-12
1700	1600	MTC1200-16
1900	1800	MTC1200-18
2100	2000	MTC1200-20
2500	2400	MTC1200-24

Symbol	Parameter	Test Conditions	$T_j(^{\circ}C)$	Rating			Units
				Min.	Typ.	Max.	
$I_{T(AV)}$	Mean on-state current	180° sine half-wave, 50Hz, single-sided heat dissipation, $T_c=70^{\circ}C$	125			1200	A
I_{FSM}	Non-repetitive on-state surge current	10ms, sine half-wave, $V_R=0.6V_{RRM}$	125			34	KA
I^2t						5780	$A^2s \cdot 10^3$
I_{DRM}	Repetitive peak off-state current	At V_{DRM}	125			60	mA
I_{RRM}	Repetitive peak reverse current	At V_{RRM}	125			60	mA
V_{TO}	On-state threshold voltage		125			0.71	V
V_{TM}	Peak on-state voltage	$I_{TM}=2400A$	25		1.4	1.7	V
R_T	Slope resistance		125			0.11	mΩ
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			1000	V/μs
di/dt	Critical rate of rise of off-state current	$V_{DM}=0.67V_{DRM}$, Gate pulse $t_r \leq 0.5\mu s$, $I_{GM}=1.5A$	125			200	A/μs
I_{GT}	Gate trigger current	$V_A=12V$, $I_A=1A$	25	30		100	mA
V_{GT}	Gate trigger voltage		25			1.8	V
I_H	Holding current		25	20		150	mA
V_{iso}	Insulation voltage	AC, 50Hz, R.M.S, 1min		2500			V
$R_{th(j-c)}$	Thermal resistance junction-case	180° sine half-wave, single die				0.026	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance case-heatsink	180° sine half-wave, single module				0.02	$^{\circ}C/W$
Mt	Terminal mounting torque			10		12	N · m
Ms	Baseplate mounting torque			10		12	N · m
T_{stg}	Storage temperature			-40		125	$^{\circ}C$



Outline package dimensions

03

